Bridging Topological Insulators, Skyrmions and Graphene (spin-orbit + topology with two-D electrons)

Albert Fert

UMR CNRS/Thales, Université Paris-Sud, Université Paris-Saclay

Albert.fert@thalesgroup.com

After the discovery of the outstanding properties of the electrons in graphene, the recent years have also seen the emergence of fascinating phenomena in other twodimensional (2D) electron systems in which they are induced by spin-orbit coupling (SOC), breaking of inversion symmetry and topology [1]. The list includes the surface/interface states of topological insulators, Rashba states, ultra-thin films with interface-induced magnetic skyrmions and 2D materials as, for example, transition metal dichalcogenides.

I will begin by a review of the recent advances on topological insulators, Rashba systems, skyrmions ... and I will describe the resulting perspective of applications that can be anticipated for the next decade. In pure graphene the SOC is very small but recent results have shown how it can be enhanced in heterostructures based on graphene to combine the high mobility of the electrons in graphene with phenomena induced by SOC. I will describe the resulting perspective.

References

[1] Review in Soumyanarayanan et al, Nature **539**, 509 (2016).

